

Notice of References Cited			Application/Control No. 10/582,707	Applicant(s)/Patent Under Reexamination TWITCHEN ET AL.
			Examiner XIAOBEI WANG	Art Unit 4181

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*	B	US-5,524,458 A	06-1996	Buchner, Michaela	63/28
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*	D	US-7,160,617	01-2007	Scarsbrook et al.	428/408
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*	N	WO 03/014427	02-2003	WIPO	Linares et al	C30B 25/02
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NON-PATENT DOCUMENTS

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*	V	Vlasov et al, Relative Abundance of Single and Vacancy-Bonded Substitutional nitrogen in CVD Diamond, 2 March 2000, phys stat sol, 181, 83-90
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*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a))
Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.